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December 2014

### FFH50US60S\_F085 50A, 600V Stealth Diode

#### **Features**

- Stealth Recovery ( t<sub>rr</sub>=163ns(Typ.) @ I<sub>F</sub>=50A )
- Low Forward Voltage(V<sub>F</sub>=1.69V(Max.) @ I<sub>F</sub>=50A)
- · Avalanche Energy Rated
- · AEC-Q101 Qualified

#### **Applications**

- · Automotive DCDC Converter
- · Automotive On Board Charger
- · Switching Power Supply
- · Power Switching Circuits

#### 50A,600V Stealth Diode

The FFH50US60S\_F085 is a Stealth  $^{\text{TM}}$  diode optimized for low loss performance in output rectification. The STEALTH  $^{\text{TM}}$  family exhibits low reverse recovery current(I<sub>RR</sub>), low V<sub>F</sub> and soft recovery under typical operating conditions. It has a low forward-voltage drop and is of silicon nitride passivated.

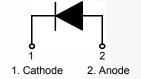
This device is intended for use as a freewheel/clamping diode in various automotive switching power supplies and other power switching applications. Its low stored charge as well as Stealth<sup>TM</sup> and soft recovery characteristics minimize ringing and electrical noise while reduce the overall power loss.

#### **Pin Assignments**



1. Cathode

2. Anode



Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

| Symbol             | Parameter   | Ratings      | Units |  |
|--------------------|---|--------------|-------|--|
| V <sub>RRM</sub>   | Peak Repetitive Reverse Voltage                           | 600          | V     |  |
| V <sub>RWM</sub>   | Working Peak Reverse Voltage 600                          |              |       |  |
| V <sub>R</sub>     | DC Blocking Voltage                                       | 600          | V     |  |
| I <sub>F(AV)</sub> | Average Rectified Forward Current @ T <sub>C</sub> = 25°C | 50           | Α     |  |
| I <sub>FSM</sub>   | Non-repetitive Peak Surge Current (Halfwave 1 Phase 50Hz) | 150          | А     |  |
| E <sub>AVL</sub>   | Avalanche Energy (1A, 40mH)                               | 20           | mJ    |  |
| $T_{J_i} T_{STG}$  | Operating Junction and Storage Temperature                | - 55 to +175 | °C    |  |

#### Thermal Characteristics T<sub>C</sub> = 25°C unless otherwise noted

| Symbol          | Parameter                                       | Max  | Units |  |
|-----------------|---|------|-------|--|
| $R_{\theta JC}$ | Maximum Thermal Resistance, Junction to Case    | 0.71 | °C/W  |  |
| $R_{\theta JA}$ | Maximum Thermal Resistance, Junction to Ambient | 30   | °C/W  |  |

#### **Package Marking and Ordering Information**

| <b>Device Marking</b>      | Device | Package   | Tube        | Quantity |  |
|----------------------------|--------|-----------|-------------|----------|--|
| FFH50US60S FFH50US60S_F085 |        | TO-247-2L | TO-247-2L - |          |  |

### **Electrical Characteristics** $T_C = 25^{\circ}C$ unless otherwise noted

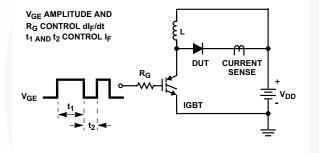
| Symbol                           | Parameter                     | Conditions  |   | Min. | Тур.         | Max          | Units    |
|----------------------------------|-------------------------------|---|---|------|--------------|--------------|----------|
| I <sub>R</sub>                   | Instantaneous Reverse Current | V <sub>R</sub> = 600V                               | T <sub>C</sub> = 25 °C                            | -    | -            | 100          | uA       |
|                                  |                               |   | T <sub>C</sub> = 175 °C                           | -    | -            | 1000         | uA       |
| V <sub>FM</sub> <sup>1</sup>     | Instantaneous Forward Voltage | I <sub>F</sub> = 50A                                | T <sub>C</sub> = 25 °C<br>T <sub>C</sub> = 175 °C | -    | 1.27<br>1.19 | 1.69<br>1.57 | V<br>V   |
| t <sub>rr</sub> <sup>2</sup>     | Reverse Recovery Time         | $I_F = 1A$ , di/dt = 200A/ $\mu$ s,<br>$V_R = 390V$ | T <sub>C</sub> = 25 °C                            | -    | 41           | 82           | ns       |
|                                  |                               | $I_F = 50A$ , di/dt = 200A/ $\mu$ s, $V_R = 390V$   | T <sub>C</sub> = 25 °C<br>T <sub>C</sub> = 175 °C | -    | 163<br>364   |              | ns<br>ns |
| t <sub>a</sub><br>t <sub>b</sub> | Reverse Recovery Time         | $I_F = 50A$ , di/dt = 200A/ $\mu$ s, $V_R = 390V$   | T <sub>C</sub> = 25 °C                            | -    | 65<br>98     | -            | ns<br>ns |
| $Q_{rr}$                         | Reverse Recovery Charge       |   |   | -    | 886          | -            | nC       |

#### Notes:

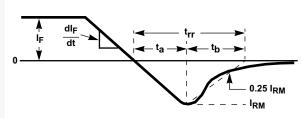
- 1. Pulse : Test Pulse width =  $300\mu s$ , Duty Cycle = 2%
- 2. Guaranteed by design

#### **Test Circuit and Waveforms**

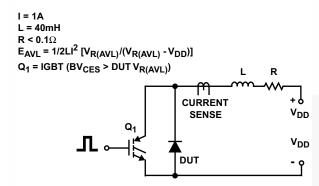
#### t<sub>rr</sub> Test Circuit



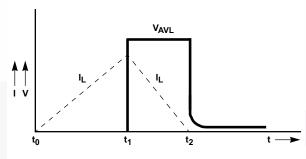
#### t<sub>rr</sub> Waveforms and Definitions



#### **Avalanche Energy Test Circuit**



#### **Avalanche Current and Voltage Waveforms**



#### **Typical Performance Characteristics**

Figure 1. Typical Forward Voltage Drop vs. Forward Current

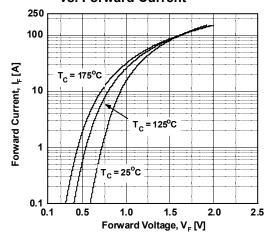


Figure 3. Typical Junction Capacitance

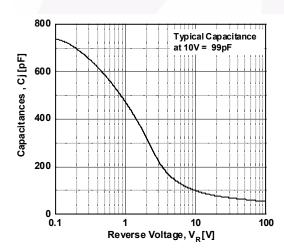


Figure 5. Typical Reverse Recovery Current vs. di/dt

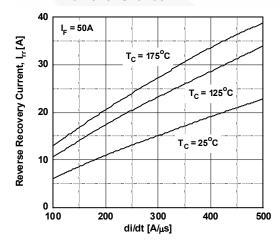


Figure 2. Typical Reverse Current vs.

Reverse Voltage

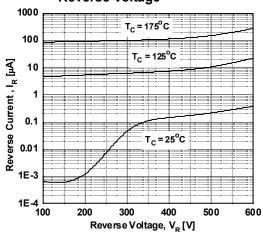


Figure 4. Typical Reverse Recovery Time vs. di/dt

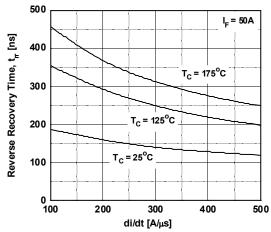
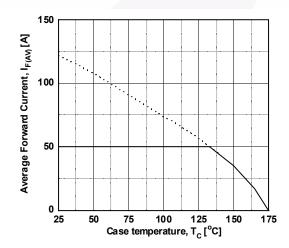


Figure 6. Forward Current Derating Curve



### **Typical Performance Characteristics** (Continued)

1000

0 L 100

5000 T<sub>C</sub> = 175°C = 50A Reverse Recovery Charge, Qrr[nC] 4000 3000 2000

Figure 7. Reverse Recovery Charge

Figure 8. Transient Thermal Response Curve

200

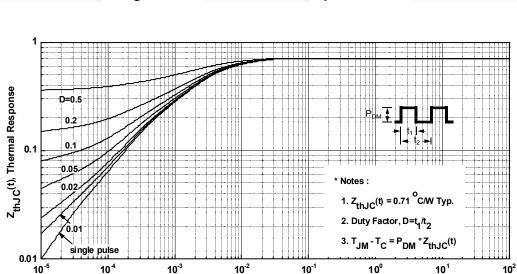
 $T_C = 25^{\circ}C$ 

300

di/dt [A/μs]

400

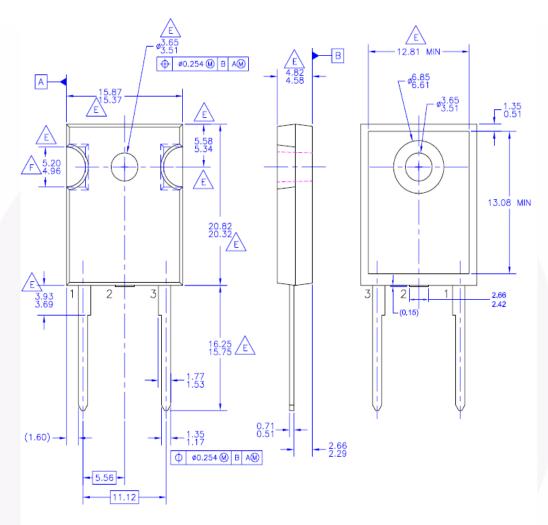
500



 $\mathbf{t_1}$ , Square Wave Pulse Duration [sec]

#### **Mechanical Dimensions**

### TO-247-2L



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Dimensions in Millimeters



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